NSN 5961-01-319-0475

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-319-0475 **Inclosure Material:** Glass **Overall Length:** 0.650 inches **Overall Diameter:** 1.565 inches **Function For Which Designed:** Rectifier **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 800.0 reverse voltage, peak **Current Rating Per Characteristic:** 400.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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